

# New Jersey Semi-Conductor Products, Inc.

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## COMPLEMENTARY SILICON PLASTIC POWER TRANSISTORS

... designed for use in general-purpose amplifier and switching applications.

### FEATURES:

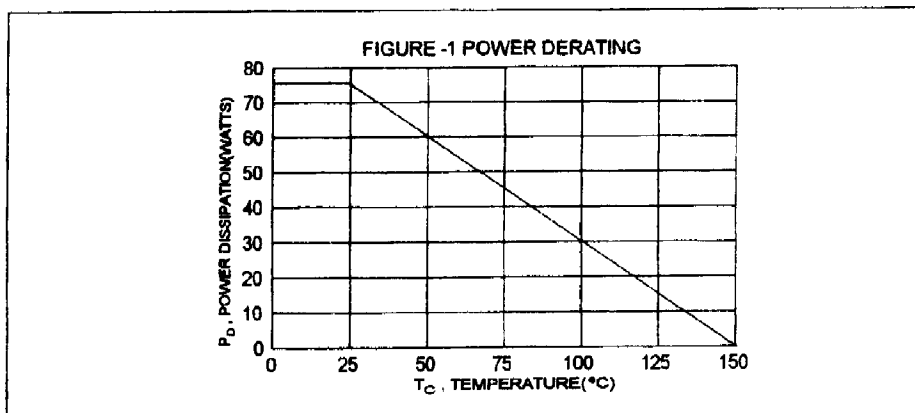
- \* Collector-Emitter Sustaining Voltage-  
 $V_{CE(sus)}$  = 40 V (Min) -2N6486, 2N6489  
 = 60 V (Min) -2N6487, 2N6490  
 = 80 V (Min) -2N6488, 2N6491
- \* DC Current Gain Specified to 15 Amperes  
 $hFE = 20-150 @ I_C = 5.0 A$   
 = 5.0 (Min) @  $I_C = 15A$

### MAXIMUM RATINGS

Characteristic	Symbol	2N6486 2N6489	2N6487 2N6490	2N6488 2N6491	Unit
Collector-Emitter Voltage	$V_{CE0}$	40	60	80	V
Collector-Base Voltage	$V_{CB0}$	50	70	90	V
Emitter-Base Voltage	$V_{EB0}$	5.0			V
Collector Current - Continuous	$I_C$	15			A
Base Current	$I_B$	5.0			A
Total Power Dissipation @ $T_C = 25^\circ C$ Derate above $25^\circ C$	$P_D$	75 0.6			W W/ $^\circ C$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-65 to +150			$^\circ C$

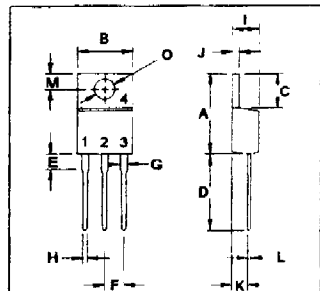
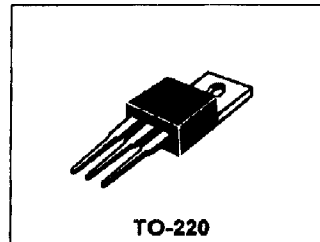
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1.67	$^\circ C/W$



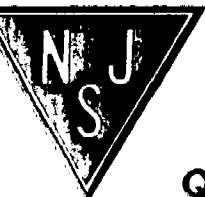
NPN	PNP
2N6486	2N6489
2N6487	2N6490
2N6488	2N6491

15 AMPERE  
COMPLEMENTARY SILICON  
POWER TRANSISTORS  
40-80 Volts  
75 Watts



PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR (CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.68
G	1.12	1.36
H	0.72	0.98
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



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**Quality Semi-Conductors**

**2N6486, 2N6487, 2N6488 NPN / 2N6489, 2N6490, 2N6491 PNP**

**ELECTRICAL CHARACTERISTICS (  $T_c = 25^\circ\text{C}$  unless otherwise noted )**

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS**

Collector - Emitter Sustaining Voltage (1) ( $I_c = 100 \text{ mA}$ , $I_B = 0$ )	2N6486, 2N6489 2N6487, 2N6490 2N6488, 2N6491	$V_{CE(sus)}$	40 60 80	V
Collector Cutoff Current ( $V_{CE} = 20 \text{ V}$ , $I_B = 0$ ) ( $V_{CE} = 30 \text{ V}$ , $I_B = 0$ ) ( $V_{CE} = 40 \text{ V}$ , $I_B = 0$ )	2N6486, 2N6489 2N6487, 2N6490 2N6488, 2N6491	$I_{CEO}$		1.0 1.0 1.0
Collector Cutoff Current ( $V_{CE} = 45 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ ) ( $V_{CE} = 65 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ ) ( $V_{CE} = 85 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ ) ( $V_{CE} = 40 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ , $T_c = 125^\circ\text{C}$ ) ( $V_{CE} = 60 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ , $T_c = 125^\circ\text{C}$ ) ( $V_{CE} = 80 \text{ V}$ , $V_{BE(off)} = 1.5 \text{ V}$ , $T_c = 125^\circ\text{C}$ )	2N6486, 2N6489 2N6487, 2N6490 2N6488, 2N6491 2N6486, 2N6489 2N6487, 2N6490 2N6488, 2N6491	$I_{CEX}$		0.5 0.5 0.5 5.0 5.0 5.0
Emitter Cutoff Current ( $V_{EB} = 5.0 \text{ V}$ , $I_C = 0$ )		$I_{EBO}$		1.0

**ON CHARACTERISTICS (1)**

DC Current Gain ( $I_c = 5.0 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ ) ( $I_c = 15 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ )		$h_{FE}$	20 5.0	150	
Collector-Emitter Saturation Voltage ( $I_c = 5.0 \text{ A}$ , $I_B = 0.5 \text{ A}$ ) ( $I_c = 15 \text{ A}$ , $I_B = 5.0 \text{ A}$ )		$V_{CE(sat)}$		1.3 3.5	V
Base-Emitter On Voltage ( $I_c = 5.0 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ ) ( $I_c = 15 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ )		$V_{BE(on)}$		1.3 3.5	V

**DYNAMIC CHARACTERISTICS**

Current-Gain-Bandwidth Product (2) ( $I_c = 1.0 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ , $f = 1.0 \text{ MHz}$ )		$f_T$	5.0		MHz
Small-Signal Current Gain ( $I_c = 1.0 \text{ A}$ , $V_{CE} = 4.0 \text{ V}$ , $f = 1.0 \text{ KHz}$ )		$h_{fe}$	15		

(1) Pulse Test: Pulse width =  $300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

(2)  $f_T = |h_{fe}| \cdot f_{test}$